		Application No.	Applicant(s)
		10/561,205	MASAHIRO SAKURADA
Notice of Allowability	. * *	Examiner	Art Unit
,		Felisa C. Hiteshew	1722
The MAILING DATE of this comm All claims being allowable, PROSECUTION ON T herewith (or previously mailed), a Notice of Allowa NOTICE OF ALLOWABILITY IS NOT A GRANT of the Office or upon petition by the applicant. Se	HE MERITS IS ance (PTOL-85) OF PATENT RI	(OR REMAINS) CLOSED in this ap or other appropriate communication GHTS. This application is subject	oplication. If not included on will be mailed in due course. THIS
1. X This communication is responsive to the amendment filed on July 30, 2007.			
2. The allowed claim(s) is/are <u>10-49</u> .			
3. Acknowledgment is made of a claim for for a) All b) Some* c) None 1. Certified copies of the priority of the certified copies of the priority of the certified copies not received: Applicant has THREE MONTHS EROM THE "M	of the: documents have documents have if the priority doc e 17.2(a)).	been received. been received in Application No cuments have been received in this	national stage application from the
Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.			
4. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient.			
5. CORRECTED DRAWINGS (as "replacement sheets") must be submitted.			
(a) ☐ including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached			
1) 🗌 hereto or 2) 🔲 to Paper No./Mail Date			
(b) ☐ including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date			
Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of a each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d).			
6. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL.			
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Attachment(s) 1. ☐ Notice of References Cited (PTO-892)		5. Notice of Informal F	Potont Application
2. ☐ Notice of Draftperson's Patent Drawing Revi	ew (PTO-948)	6. X Interview Summary	• •
3. Information Disclosure Statements (PTO/SB.	/08),	Paper No./Mail Da 7. 🛣 Examiner's Amend	ite
Paper No./Mail Date 4. Examiner's Comment Regarding Requireme of Biological Material	•		ent of Reasons for Allowance
	.e 	9.	Felisa C. Hiteshew Primary Examiner Art Unit: 1722

U.S. Patent and Trademark Office PTOL-37 (Rev. 08-06)

EXAMINER'S AMENDMENT

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone interview with Andrew B Freistein on September 7, 2007.

The application has been amended as follows:

In the specification, after the title, please insert the following:

-- This application is a 371 of PCT/JP04/07349 05/28/2004 --.

In the Abstract: Please cancel the current abstract and insert the newly submitted abstract.

In the claims: Please cancel claims 50-57

Allowable Subject Matter

- 1. Claims 10-49 are allowed.
- 2. The following is an examiner's statement of reasons for allowance: The most relevant prior art or reference is that of Sakurada, et al '260 B2. However, it does not teach nor fairly suggest singularly or in any combination thereof a method for producing a single crystal with pulling the single crystal from a raw material melt in a chamber by Czochralski method, wherein when growing the single crystal, where a pulling rate is defined as V (mm/min), a temperature gradient of the crystal at the vicinity of solid-liquid interface at a central portion of the crystal is defined as Gc (*C/mm), and a temperature

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gradient of the crystal at the vicinity of solid-liquid interface at a peripheral portion of the crystal is defined as Ge(*C/mm) during growing a straight body of the single crystal, during pulling the single crystal, the temperature gradient Gc of the crystal at the central portion of the crystal are controlled by changing a distance between a melt surface of the raw material melt and a heat insulating member provided in the chamber so as to oppose to the surface of the raw material melt, thereby G = I(Gc - Ge)I which is difference between the temperature gradient Gc at the central portion of the crystal and the temperature gradient Ge at the peripheral portion of the crystal is 0.5*C/mm or less, and also V/Gc (mm²/*C x min) which is a ratio of the pulling rate V and the temperature gradient Gc at the central portion of the crystal is controlled so that a single crystal including a desired defect region is grown.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Felisa Hiteshew whose telephone number is (571) 272-1463. The examiner can normally be reached on Mondays through Thursday from 5:30 AM to 4:00 PM with Fridays off.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Yogendra Gupta, can be reached on (571) 272-1316. The fax phone number for the organization where this application or proceeding is

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assigned is (571) 273-1463.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system. see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866- 217-9197 (toll-free).

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